

## **Application Data Sheet**

### **Application Information**

Application Type::	Regular
Subject Matter::	Utility
Suggested Group Art Unit::	N/A
CD-ROM or CD-R?::	None
Sequence submission?::	None
Computer Readable Form (CRF)?::	No
Title::	MEMORY DEVICE IN SEMICONDUCTOR FOR ENHANCING ABILITY OF TEST
Attorney Docket Number::	29926/39501
Request for Early Publication?::	No
Request for Non-Publication?::	No
Small Entity?::	No
Petition included?::	No
Secrecy Order in Parent Appl.?::	No

### **Applicant Information**

Applicant Authority Type::	Inventor
Primary Citizenship Country::	Korea, Republic of
Status::	Full Capacity
Given Name::	Byung-Jae
Family Name::	Lee
City of Residence::	Kyoungki-Do
Country of Residence::	Korea
Street of mailing address::	San 136-1, Ami-ri, Bubal-eub Ichon-shi
City of mailing address::	Kyoungki-Do
Country of mailing address::	Korea, Republic of
Postal or Zip Code of mailing address::	467-860

**Correspondence Information**

Correspondence Customer Number:: 04743

**Representative Information**

Representative Customer Number:: 04743

**Foreign Priority Information**

Country::	Application number::	FilingDate::	Priority Claimed::
Korea, Republic of	2002-66919	10/31/02	Yes

**Assignee Information**

Assignee name:: HYNIX SEMICONDUCTOR INC.  
Street of mailing address:: San 136-1, Ami-Ri, Bubal-Eub, Ichon-Shi  
City of mailing address:: Kyoungki-Do  
Country of mailing address:: Korea, Republic of  
Postal or Zip Code of mailing address:: 467-860